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FGH20N60UFD 600 V, 20 A Field Stop IGBT

Features

- High Current Capability
- Low Saturation Voltage: V_{CE(sat)} =1.8 V @ I_C = 20 A
- High Input Impedance
- Fast Switching
- RoHS Compliant

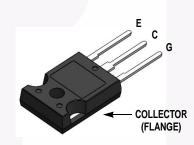
Applications

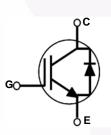
• Solar Inverter, UPS, Welder, PFC

March 2015

General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit	
V _{CES}	Collector to Emitter Voltage		600	V	
V _{GES}	Gate to Emitter Voltage	±20	V		
	Transient Gate-to-Emitter Voltage	±30	V		
la.	Collector Current	@ T _C = 25°C	40	A	
I _C	Collector Current	@ T _C = 100 ^o C	20	А	
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	60	А	
IF	Diode Forward Current	@ T _C = 25 ^o C	20	А	
	Diode Forward Current	10	А		
I _{FM (1)}	Pulsed Diode Maximum Forward Cu	60	А		
P _D	Maximum Power Dissipation	@ T _C = 25 ^o C	165	W	
	Maximum Power Dissipation	@ T _C = 100°C	66	W	
TJ	Operating Junction Temperature	-55 to +150			
T _{stg}	Storage Temperature Range		-55 to +150	°C	
Τ _L	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 second	300	°C		

Notes:

1: Repetitive rating: Pulse width limited by max. junction temperature

Part NumberTop MarkPackageFGH20N60UFDTUFGH20N60UFDTO-247		Top Mark	Package	Packing Method	Reel Size	Т	Tape Width		Quantity	
		Tube N/A		A N/A		30				
Electric	al Ch	aracteristics	s of the IC	GBT $T_{C} = 25^{\circ}C$ unless other	wise noted					
Symbol		Parameter	•	Test Conditio	ns M	in.	Тур.	Max.	Unit	
-	Ļ						ļ			
Off Charac	1									
BV _{CES}	Collector to Emitter Breakdown Voltage		$V_{GE} = 0 V, I_{C} = 250 \mu A$		00	-	-	V		
ΔBV_{CES} / ΔT_{J}	Temperature Coefficient of Breakdown Voltage		V_{GE} = 0 V, I _C = 250 μ A		-	0.6	-	V/ºC		
I _{CES}	Collector Cut-Off Current		$V_{CE} = V_{CES}, V_{GE} = 0 V$				250	μA		
I _{GES}	G-E Le	G-E Leakage Current		$V_{GE} = V_{GES}, V_{CE} = 0 V$		-	- ±4		nA	
On Charac	teristics									
V _{GE(th)}	1	reshold Voltage		I _C = 250 μA, V _{CE} = V _{GE}	4	.0	5.0	6.5	V	
0=(11)		5		$I_{\rm C} = 20$ A, $V_{\rm GE} = 15$ V		-	1.8	2.4	V	
V _{CE(sat)}	Collecto	Collector to Emitter Saturation Voltage		$I_{\rm C} = 20 \text{ A}, V_{\rm GE} = 15 \text{ V},$ $T_{\rm C} = 125^{\circ}\text{C}$		-	2.0	-	V	
Dynamic C	1						0.40	_	~	
C _{ies}	-	apacitance		V _{CE} = 30 V, V _{GE} = 0 V,		-	940	-	pF	
C _{oes}		Capacitance		f = 1 MHz		-	110	-	pF	
C _{res}	Revers	e Transfer Capacita	ance			-	40	-	pF	
Switching	Charact	eristics								
t _{d(on)}	1	n Delay Time				-	13	-	ns	
t _r	Rise Ti	me		-		-	17	-	ns	
t _{d(off)}	Turn-O	ff Delay Time		V _{CC} = 400 V, I _C = 20 A,		-	87	-	ns	
t _f	Fall Tim			$R_{G} = 10 \Omega, V_{GE} = 15 V,$		-	32		ns	
Eon	Turn-O	n Switching Loss		Inductive Load, T _C = 25 ^c	°C	-	0.38	-	mJ	
E _{off}	Turn-O	ff Switching Loss		-		-	0.26	-	mJ	
E _{ts}	Total Sv	witching Loss		-		- /	0.64	-	mJ	
t _{d(on)}	Turn-O	n Delay Time				_	13	- /	ns	
t _r	Rise Ti	me				-	16	-	ns	
t _{d(off)}	Turn-O	ff Delay Time		V _{CC} = 400 V, I _C = 20 A,		-	92	-	ns	
t _f	Fall Tim	ne		$R_{G} = 10 \Omega$, $V_{GE} = 15 V$,	-0.0	-	63	-	ns	
E _{on}	Turn-O	n Switching Loss		Inductive Load, T _C = 125	5.6	-	0.41	- /	mJ	
E _{off}	Turn-O	ff Switching Loss		1		-	0.36	-	mJ	
E _{ts}	Total Sv	witching Loss				-	0.77	- \	mJ	
Qg	Total G	ate Charge				-	63	-	nC	
Q _{ge}	Gate to	Emitter Charge		$V_{CE} = 400 \text{ V}, I_{C} = 20 \text{ A},$		-	7	-	nC	
Q _{gc}	Gate to	Collector Charge		V _{GE} = 15 V		-	32	-	nC	

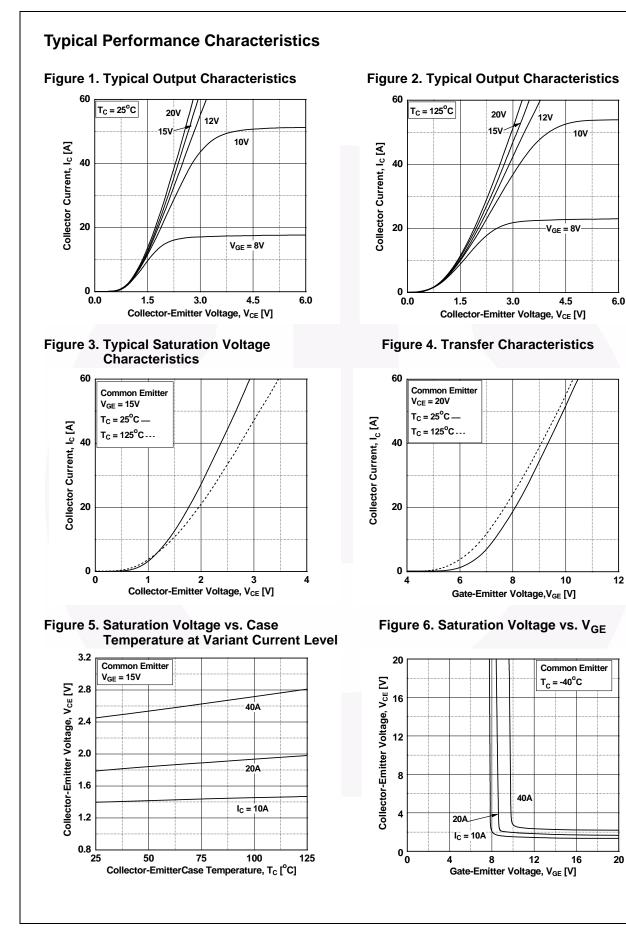
Thermal Characteristics

Symbol Parameter		Тур.	Max.	Unit	
$R_{\theta JC}(IGBT)$	Thermal Resistance, Junction to Case	-	0.76	°C/W	
$R_{\theta JC}$ (Diode)	Thermal Resistance, Junction to Case	-	2.51	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient	-	40	°C/W	

Electrical Characteristics of the Diode $T_{C} = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Conditions		Min.	Тур.	Max	Unit	
V _{FM}	Diode Forward Voltage	I _F = '	10 A	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	1.9	2.5	V
				$T_{C} = 125^{\circ}C$	-	1.7	-	
t _{rr}	Diode Reverse Recovery Time			$T_C = 25^{\circ}C$	-	34	-	ns
		I_ = '	10 A, di _F /dt = 200 A/µs	$T_{C} = 125^{\circ}C$	-	57	-	
Q _{rr}	Diode Reverse Recovery Charge	ч <u>н</u> —	10 / ι, αιμ/αι – 200 / ιμο	$T_C = 25^{\circ}C$	-	41	-	nC
	enalge			$T_{C} = 125^{\circ}C$	-	96	-	

3



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Typical Performance Characteristics

Figure 7. Saturation Voltage vs. V_{GE}

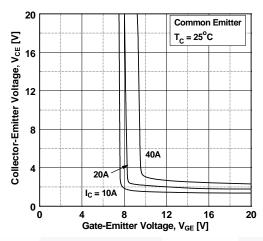


Figure 9. Capacitance Characteristics

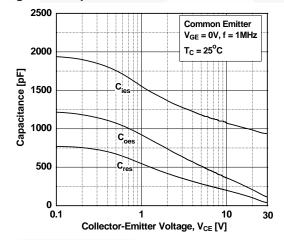


Figure 11. SOA Characteristics

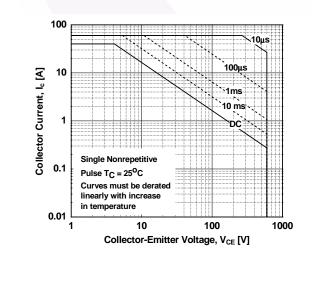


Figure 8. Saturation Voltage vs. V_{GE}

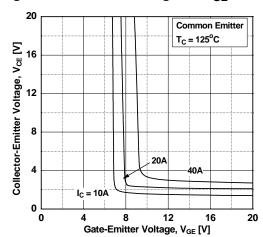


Figure 10. Gate charge Characteristics

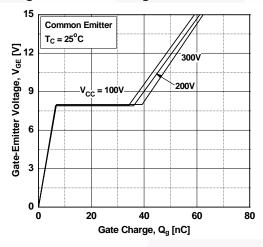
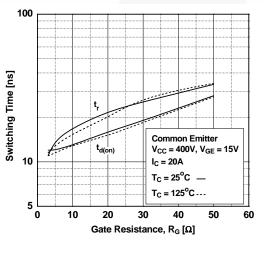
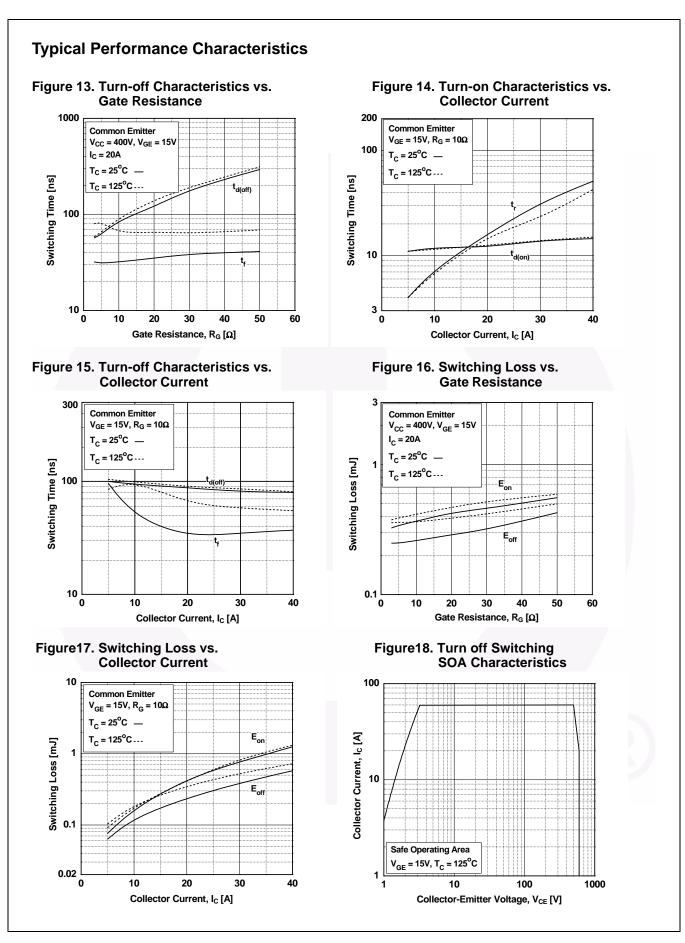
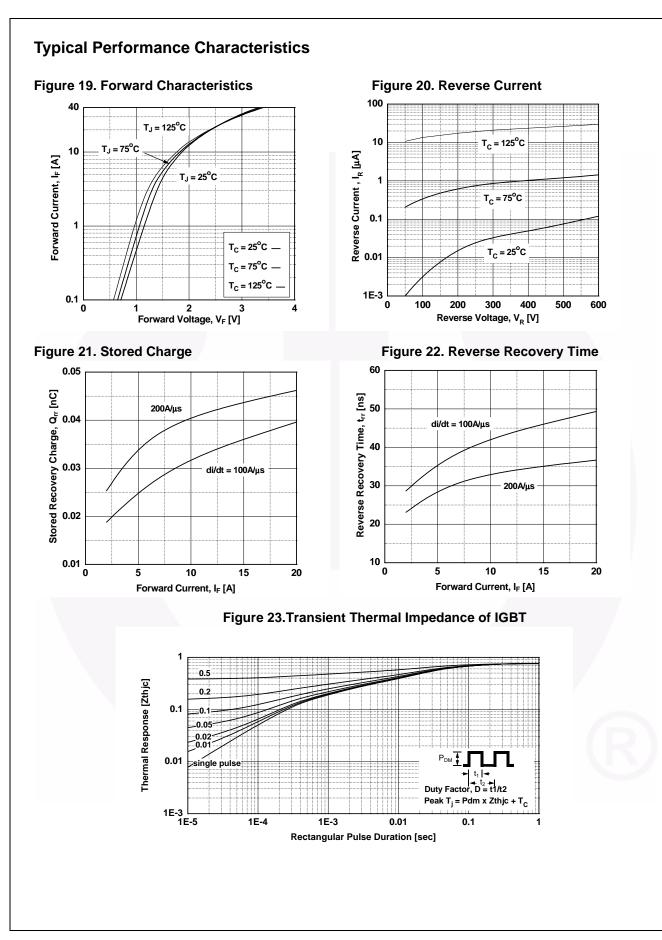


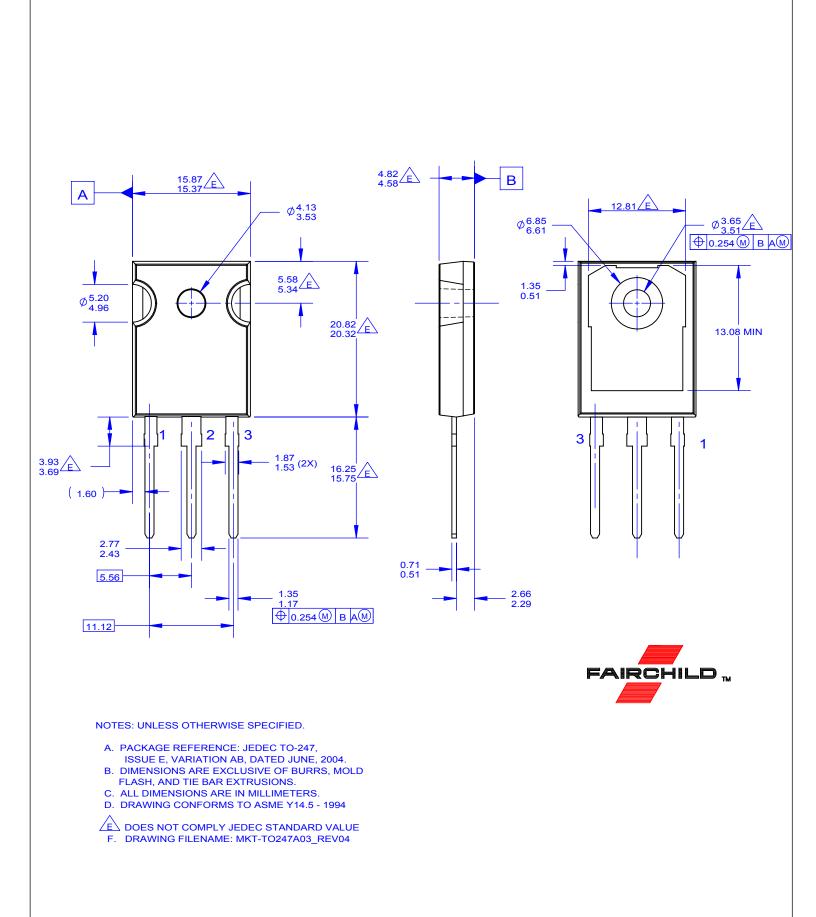
Figure 12. Turn-on Characteristics vs. Gate Resistance





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